# **QL4009 QuickRAM Data Sheet**



••••••9,000 Usable PLD Gate QuickRAM ESP Combining Performance, Density and Embedded RAM

## **Device Highlights**

### **High Performance & High Density**

- 9,000 Usable PLD Gates with 82 I/Os
- 300 MHz 16-bit Counters, 400 MHz Datapaths, 160+ MHz FIFOs
- 0.35 µm four-layer metal non-volatile CMOS process for smallest die sizes

### High Speed Embedded SRAM

- 8 dual-port RAM modules, organized in user-configurable 1,152 bit blocks
- 5 ns access times, each port independently accessible
- Fast and efficient for FIFO, RAM, and ROM functions

### Easy to Use / Fast Development Cycles

- 100% routable with 100% utilization and complete pin-out stability
- Variable-grain logic cells provide high performance and 100% utilization
- Comprehensive design tools include high quality Verilog/VHDL synthesis

### **Advanced I/O Capabilities**

- Interfaces with both 3.3 V and 5.0 V devices
- PCI compliant with 3.3 V and 5.0 V busses for -1/-2/-3/-4 speed grades
- Full JTAG boundary scan
- I/O Cells with individually controlled Registered Input Path and Output Enables

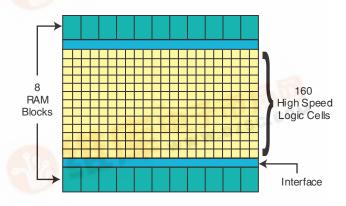


Figure 1: QuickRAM Block Diagram



### **Architecture Overview**

The QuickRAM<sup>TM</sup> family of ESPs (Embedded Standard Products) offers FPGA logic in combination with Dual-Port SRAM modules. The QL4009 is a 9,000 usable PLD gate member of the QuickRAM family of ESPs. QuickRAM ESPs are fabricated on a 0.35µm four-layer metal process using QuickLogic's patented ViaLink<sup>TM</sup> technology to provide a unique combination of high performance, high density, low cost, and extreme ease-of-use.

The QL4009 contains 160 logic cells and 8 Dual Port RAM modules (see **Figure 1**). Each RAM module has 1,152 RAM bits, for a total of 9,216 bits. RAM Modules are Dual Port (one read port, one write port) and can be configured into one of four modes: 64 (deep) x18 (wide), 128x9, 256x4, or 512x2 (see **Figure 4**). With a maximum of 82 I/Os, the QL4009 is available in 68-pin PLCC, 84-pin PLCC and 100-pin TQFP packages.

Designers can cascade multiple RAM modules to increase the depth or width allowed in single modules by connecting corresponding address lines together and dividing the words between modules (see **Figure 2**). This approach allows up to 512-deep configurations as large as 16 bits wide in the smallest QuickRAM device and 44 bits wide in the largest device.

Software support for the complete QuickRAM family, including the QL4009, is available through two basic packages. The turnkey QuickWorks<sup>TM</sup> package provides the most complete ESP software solution from design entry to logic synthesis, to place and route, to simulation. The QuickTools<sup>TM</sup> packages provides a solution for designers who use Cadence, Exemplar, Mentor, Synopsys, Synplicity, Viewlogic, Aldec, or other third-party tools for design entry, synthesis, or simulation.

The QuickLogic variable grain logic cell features up to 16 simultaneous inputs and 5 outputs within a cell that can be fragmented into 5 independent cells. Each cell has a fan-in of 29 including register and control lines (see **Figure 3**).

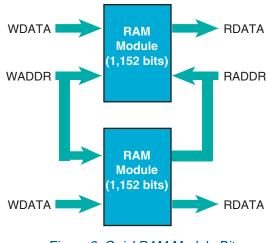


Figure 2: QuickRAM Module Bits

### **Product Summary**

### Total of 82 I/O Pins

- 74 bi-directional input/output pins, PCI-compliant for 5.0 V and 3.3 V buses for  $^{-1/-2/-3/-4}$  speed grades
- 8 high-drive input/distributed network pins

### **Eight Low-Skew Distributed Networks**

- Two array clock/control networks available to the logic cell flip-flop clock, set and reset inputs each driven by an input-only pin
- Six global clock/control networks available to the logic cell F1, clock, set and reset inputs and the input and I/O register clock, reset and enable inputs as well as the output enable control each driven by an input-only or I/O pin, or any logic cell output or I/O cell feedback

### **High Performance Silicon**

- Input + logic cell + output total delays under 6 ns
- Data path speeds over 400 MHz
- Counter speeds over 300 MHz
- FIFO speeds over 160+ MHz

## AC Characteristics at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25 $^{\circ}$ C (K = 1.00)

To calculate delays, multiply the appropriate K factor from **Table 10: Operating Range** by the following numbers in the tables provided.

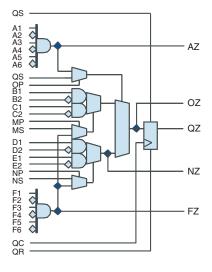


Figure 3: QuickRAM Logic Cell

| Symbol             | Parameter                        | Propagation Delays (ns)<br>Fanout (5) |     |     |     |     |
|--------------------|----------------------------------|---------------------------------------|-----|-----|-----|-----|
|                    |                                  | 1                                     | 2   | 3   | 4   | 5   |
| t <sub>PD</sub>    | Combinatorial Delay <sup>a</sup> | 1.4                                   | 1.7 | 1.9 | 2.2 | 3.2 |
| t <sub>SU</sub>    | Setup Time <sup>a</sup>          | 1.7                                   | 1.7 | 1.7 | 1.7 | 1.7 |
| t <sub>H</sub>     | Hold Time                        | 0.0                                   | 0.0 | 0.0 | 0.0 | 0.0 |
| t <sub>CLK</sub>   | Clock to Q Delay                 | 0.7                                   | 1.0 | 1.2 | 1.5 | 2.5 |
| t <sub>CWHI</sub>  | Clock High Time                  | 1.2                                   | 1.2 | 1.2 | 1.2 | 1.2 |
| t <sub>CWLO</sub>  | Clock Low Time                   | 1.2                                   | 1.2 | 1.2 | 1.2 | 1.2 |
| t <sub>SET</sub>   | Set Delay                        | 1.0                                   | 1.3 | 1.5 | 1.8 | 2.8 |
| t <sub>RESET</sub> | Reset Delay                      | 0.8                                   | 1.1 | 1.3 | 1.6 | 2.6 |
| t <sub>sw</sub>    | Set Width                        | 1.9                                   | 1.9 | 1.9 | 1.9 | 1.9 |
| t <sub>RW</sub>    | Reset Width                      | 1.8                                   | 1.8 | 1.8 | 1.8 | 1.8 |

#### Table 1: Logic Cell

a. These limits are derived from a representative selection of the slowest paths through the Quick-RAM logic cell including typical net delays. Worst case delay values for specific paths should be determined from timing analysis of your particular design.

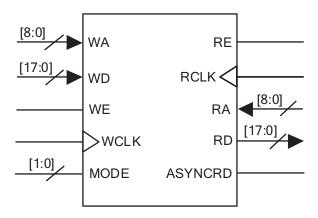


Figure 4: QuickRAM Module

| Table | 2: | RAM | Cell    | S     | ynchronous | Write | Timina |
|-------|----|-----|---------|-------|------------|-------|--------|
|       | _  |     | · · · · | · · · | ,          |       |        |

| Symbol            | Parameter                       | Propagation Delays (ns)<br>Fanout |     |     |     |     |
|-------------------|---------------------------------|-----------------------------------|-----|-----|-----|-----|
|                   |                                 | 1                                 | 2   | 3   | 4   | 5   |
| t <sub>SWA</sub>  | WA Setup Time to WCLK           | 1.0                               | 1.0 | 1.0 | 1.0 | 1.0 |
| t <sub>HWA</sub>  | WA Hold Time to WCLK            | 0.0                               | 0.0 | 0.0 | 0.0 | 0.0 |
| t <sub>SWD</sub>  | WD Setup Time to WCLK           | 1.0                               | 1.0 | 1.0 | 1.0 | 1.0 |
| t <sub>HWD</sub>  | WD Hold Time to WCLK            | 0.0                               | 0.0 | 0.0 | 0.0 | 0.0 |
| t <sub>SWE</sub>  | WE Setup Time to WCLK           | 1.0                               | 1.0 | 1.0 | 1.0 | 1.0 |
| t <sub>HWE</sub>  | WE Hold Time to WCLK            | 0.0                               | 0.0 | 0.0 | 0.0 | 0.0 |
| t <sub>WCRD</sub> | WCLK to RD (WA=RA) <sup>a</sup> | 5.0                               | 5.3 | 5.6 | 5.9 | 7.1 |

a. Stated timing for worst case Propagation Delay over process variation at  $V_{CC} = 3.3$  V and  $T_A = 25^{\circ}$  C. Multiply by the appropriate Delay Factor, K, for speed grade, voltage and temperature settings as specified in the Operating Range.

| Symbol            | Parameter               | Propagation Delays (ns)<br>Fanout |     |     |     |     |  |
|-------------------|-------------------------|-----------------------------------|-----|-----|-----|-----|--|
| Logic Cells       |                         | 1                                 | 2   | 3   | 4   | 5   |  |
| t <sub>SRA</sub>  | RA Setup Time to RCLK   | 1.0                               | 1.0 | 1.0 | 1.0 | 1.0 |  |
| t <sub>HRA</sub>  | RA Hold Time to RCLK    | 0.0                               | 0.0 | 0.0 | 0.0 | 0.0 |  |
| t <sub>SRE</sub>  | RE Setup Time to RCLK   | 1.0                               | 1.0 | 1.0 | 1.0 | 1.0 |  |
| t <sub>HRE</sub>  | RE Hold Time to RCLK    | 0.0                               | 0.0 | 0.0 | 0.0 | 0.0 |  |
| t <sub>RCRD</sub> | RCLK to RD <sup>a</sup> | 4.0                               | 4.3 | 4.6 | 4.9 | 6.1 |  |

Table 3: RAM Cell Synchronous Read Timing

a. Stated timing for worst case Propagation Delay over process variation at V<sub>CC</sub> = 3.3 V and TA =  $25^{\circ}$  C. Multiply by the appropriate Delay Factor, K, for speed grade, voltage and temperature settings as specified in the Operating Range.

| Symbol | Parameter             | Propagation Delays (ns)<br>Fanout |     |     |     |     |  |  |
|--------|-----------------------|-----------------------------------|-----|-----|-----|-----|--|--|
|        |                       | 1                                 | 2   | 3   | 4   | 5   |  |  |
| RPDRD  | RA to RD <sup>a</sup> | 3.0                               | 3.3 | 3.6 | 3.9 | 5.1 |  |  |

#### Table 4: RAM Cell Asynchronous Read Timing

a. Stated timing for worst case Propagation Delay over process variation at  $V_{CC}$  = 3.3 V and TA = 25° C. Multiply by the appropriate Delay Factor, K, for speed grade, voltage and temperature settings as specified in the Operating Range.

| Symbol            | Parameter                              |     | Propagation Delays (ns)<br>Fanout |     |     |     |     |     |  |  |  |
|-------------------|--|-----|-----------------------------------|-----|-----|-----|-----|-----|--|--|--|
|                   |  | 1   | 2                                 | 3   | 4   | 8   | 12  | 24  |  |  |  |
| t <sub>IN</sub>   | High Drive Input Delay                 | 1.5 | 1.6                               | 1.8 | 1.9 | 2.4 | 2.9 | 4.4 |  |  |  |
| t <sub>INI</sub>  | High Drive Input, Inverting Delay      | 1.6 | 1.7                               | .19 | 2.0 | 2.5 | 3.0 | 4.5 |  |  |  |
| t <sub>ISU</sub>  | Input Register Set-Up Time             |     | 3.1                               | 3.1 | 3.1 | 3.1 | 3.1 | 3.1 |  |  |  |
| t <sub>IH</sub>   | Input Register Hold Time               | 0.0 | 0.0                               | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 |  |  |  |
| t <sub>ICLK</sub> | Input Register Clock To Q              | 0.7 | 0.8                               | 1.0 | 1.1 | 1.6 | 2.1 | 3.6 |  |  |  |
| t <sub>IRST</sub> | Input Register Reset Delay             | 0.6 | 0.7                               | 0.9 | 1.0 | 1.5 | 2.0 | 3.5 |  |  |  |
| t <sub>IESU</sub> | Input Register Clock Enable Setup Time | 2.3 | 2.3                               | 2.3 | 2.3 | 2.3 | 2.3 | 2.3 |  |  |  |
| t <sub>IEH</sub>  | Input Register Clock Enable Hold Time  | 0.0 | 0.0                               | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 |  |  |  |

#### Table 5: Input-Only / Clock Cells

#### Table 6: Clock Cells

| Symbol            | Parameter                 | Propagation Delays (ns)<br>Fanout <sup>a</sup> |     |     |     |     |     |     |
|-------------------|---------------------------|--|-----|-----|-----|-----|-----|-----|
|                   |                           | 1  | 2   | 3   | 4   | 8   | 10  | 11  |
| t <sub>ACK</sub>  | Array Clock Delay         | 1.2  | 1.2 | 1.3 | 1.3 | 1.5 | 1.6 | 1.7 |
| t <sub>GCKP</sub> | Global Clock Pin Delay    | 0.7  | 0.7 | 0.7 | 0.7 | 0.7 | 0.7 | 0.7 |
| t <sub>GCKB</sub> | Global Clock Buffer Delay | 0.8  | 0.8 | 0.9 | 0.9 | 1.1 | 1.2 | 1.3 |

a. The array distributed networks consist of 40 half columns and the global distributed networks consist of 44 half columns, each driven by an independent buffer. The number of half columns used does not affect clock buffer delay. The array clock has up to 8 loads per half column. The global clock has up to 11 loads per half column.

| Symbol             | Parameter                               | Propagation Delays (ns<br>Fanout <sup>a</sup> |     |     | ;)  |     |     |
|--------------------|---|---|-----|-----|-----|-----|-----|
|                    |   | 1   | 2   | 3   | 4   | 8   | 10  |
| t <sub>I/O</sub>   | Input Delay (bidirectional pad)         | 1.3   | 1.6 | 1.8 | 2.1 | 3.1 | 3.6 |
| t <sub>ISU</sub>   | nput Register Set-Up Time               |   | 3.1 | 3.1 | 3.1 | 3.1 | 3.1 |
| t <sub>IH</sub>    | Input Register Hold Time                | 0.0   | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 |
| t <sub>IOCLK</sub> | Input Register Clock to Q               | 0.7   | 1.0 | 1.2 | 1.5 | 2.5 | 3.0 |
| t <sub>IORST</sub> | Input Register Reset Delay              | 0.6   | 0.9 | 1.1 | 1.4 | 2.4 | 2.9 |
| t <sub>IESU</sub>  | Input Register Clock Enable Set-Up Time | 2.3   | 2.3 | 2.3 | 2.3 | 2.3 | 2.3 |
| t <sub>IEH</sub>   | Input Register Clock Enable Hold Time   | 0.0   | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 |

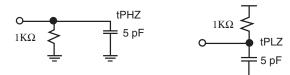
#### Table 7: I/O Cell Input Delays

a. Stated timing for worst case Propagation Delay over process variation at V<sub>CC</sub> = 3.3 V and  $T_A = 25^{\circ}$  C. Multiply by the appropriate Delay Factor, K, for speed grade, voltage and temperature settings as specified in the Operating Range.

#### Table 8: I/O Cell Output Delays

| Symbol             | Parameter                                   | Propagation Delays (ns)<br>Output Load Capacitance (pF) |     |     |     |     |
|--------------------|---|---|-----|-----|-----|-----|
|                    |   | 3   | 50  | 75  | 100 | 150 |
| t <sub>OUTLH</sub> | Output Delay Low to High                    | 2.1   | 2.5 | 3.1 | 3.6 | 4.7 |
| t <sub>OUTHL</sub> | Output Delay High to Low                    | 2.2   | 2.6 | 3.2 | 3.7 | 4.8 |
| t <sub>PZH</sub>   | Output Delay Tri-state to High              | 1.2   | 1.7 | 2.2 | 2.8 | 3.9 |
| t <sub>PZL</sub>   | Output Delay Tri-state to Low               | 1.6   | 2.0 | 2.6 | 3.1 | 4.2 |
| t <sub>PHZ</sub>   | Output Delay High to Tri-state <sup>a</sup> | 2.0   | -   | -   | -   | -   |
| t <sub>PLZ</sub>   | Output Delay High to Tri-state <sup>a</sup> | 1.2   | -   | -   | -   | -   |

a. The following loads are used for  $t_{\mbox{\scriptsize PXZ}}$ 



### **DC Characteristics**

The DC specifications are provided in the tables below.

#### Table 9: Absolute Maximum Ratings

| Parameter                 | Value                              | Parameter           | Value             |
|---------------------------|------------------------------------|---------------------|-------------------|
| V <sub>CC</sub> Voltage   | -0.5 to 4.6 V                      | DC Input Current    | ±20 mA            |
| V <sub>CCIO</sub> Voltage | -0.5 to 7.0 V                      | ESD Pad Protection  | ±2000V            |
| Input Voltage             | -0.5 V to V <sub>CCIO</sub> +0.5 V | Storage Temperature | -65° C to +150° C |
| Latch-up Immunity         | ±200 mA                            | Lead Temperature    | 300° C            |

#### Table 10: Operating Range

| Symbol            | Par                         | ameter         | Mili | itary | Indu | strial | Commercial |      | Unit |
|-------------------|-----------------------------|----------------|------|-------|------|--------|------------|------|------|
|                   |                             |                | Min  | Max   | Min  | Мах    | Min        | Max  |      |
| V <sub>CC</sub>   | Supply Voltage              |                | 3.0  | 3.6   | 3.0  | 3.6    | 3.0        | 3.6  | V    |
| V <sub>CCIO</sub> | I/O Input Tolerance Voltage |                | 3.0  | 5.5   | 3.0  | 5.5    | 3.0        | 5.25 | V    |
| T <sub>A</sub>    | Ambient Temperature         |                | -55  | -     | -40  | 85     | 0          | 70   | °C   |
| T <sub>C</sub>    | Case Temperature            |                | -    | 125   | -    | -      | -          | -    | °C   |
|                   |                             | -0 Speed Grade | 0.42 | 2.03  | 0.43 | 1.90   | 0.46       | 1.85 | n/a  |
|                   |                             | -1 Speed Grade | 0.42 | 1.64  | 0.43 | 1.54   | 0.46       | 1.50 | n/a  |
| К                 | Delay Factor                | -2 Speed Grade | 0.42 | 1.37  | 0.43 | 1.28   | 0.46       | 1.25 | n/a  |
|                   |                             | -3 Speed Grade |      |       | 0.43 | 0.90   | 0.46       | 0.88 | n/a  |
|                   |                             | -4 Speed Grade |      |       | 0.43 | 0.82   | 0.46       | 0.80 | n/a  |

| Symbol            | Parameter                                 | Conditions                             | Min                | Max                | Units |
|-------------------|---|--|--------------------|--------------------|-------|
| V <sub>IH</sub>   | Input HIGH Voltage                        |  | $0.5V_{CC}$        | $V_{CCIO}$ +0.5    | V     |
| V <sub>IL</sub>   | Input LOW Voltage                         |  | -0.5               | 0.3V <sub>CC</sub> | V     |
| V                 | Output HIGH Voltage                       | I <sub>OH</sub> = -12 mA               | 2.4                |                    | V     |
| V <sub>OH</sub>   | Output I not I vonage                     | I <sub>OH</sub> = -500 μA              | 0.9V <sub>CC</sub> |                    | V     |
| V                 | Output LOW Voltage                        | $I_{OL} = 16 \text{ mA}^{a}$           |                    | 0.45               | V     |
| V <sub>OL</sub>   | Output LOW Voltage                        | $I_{OL} = 1.5 \text{ mA}$              |                    | $0.1 V_{CC}$       | V     |
| II                | I or I/O Input Leakage Current            | $V_{I} = V_{CCIO} \text{ or } GND$     | -10                | 10                 | μA    |
| I <sub>OZ</sub>   | 3-State Output Leakage Current            | $V_{I} = V_{CCIO} \text{ or } GND$     | -10                | 10                 | μA    |
| CI                | Input Capacitance <sup>b</sup>            |  |                    | 10                 | pF    |
| т                 | Output Short Circuit Current <sup>c</sup> | $V_0 = GND$                            | -15                | -180               | mA    |
| I <sub>OS</sub>   | Output Short Circuit Current              | $V_{\rm O} = V_{\rm CC}$               | 40                 | 210                | mA    |
| I <sub>CC</sub>   | D.C. Supply Current <sup>d</sup>          | $V_{I}$ , $V_{IO}$ = $V_{CCIO}$ or GND | 0.50 (typ)         | 2                  | mA    |
| I <sub>CCIO</sub> | D.C. Supply Current on $V_{\text{CCIO}}$  |  | 0                  | 100                | μA    |

#### Table 11: DC Characteristics

a. Applies only to -1/-2/-3/-4 commercial grade devices. These speed grades are also PCI-compliant. All other devices have 8 mA IOL specifications.

b. Capacitance is sample tested only. Clock pins are 12 pF maximum.

c. Only one output at a time. Duration should not exceed 30 seconds.

d. For -1/-2/-3/-4 commercial grade devices only. Maximum ICC is 3 mA for -0 commercial grade and all industrial grade devices. and 5 mA for all military grade devices. For AC conditions, contact QuickLog-ic customer applications group.

## Kv and Kt Graphs

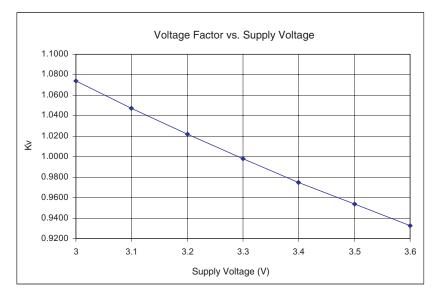


Figure 5: Voltage Factor vs. Supply Voltage

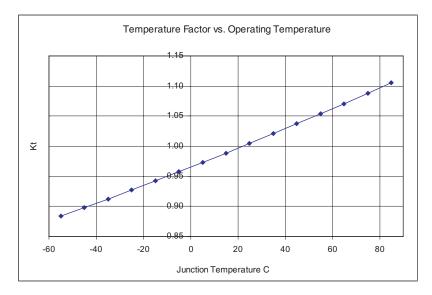


Figure 6: Temperature Factor vs. Operating Temperature

### **Power-up Sequencing**

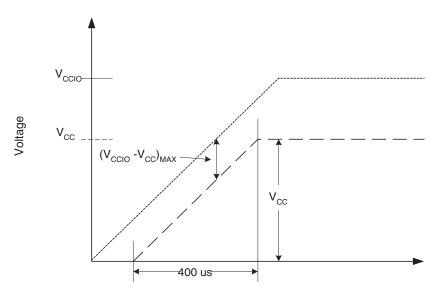




Figure 7: Power-up Requirements

The following requirements must be met when powering up the device:

(Refer to Figure 7 above)

- When ramping up the power supplies keep (V<sub>CCIO</sub> -V<sub>CC</sub>)<sub>MAX</sub>  $\leq$  500 mV. Deviation from this recommendation can cause permanent damage to the device.
- $V_{CCIO}$  must lead  $V_{CC}$  when ramping the device.
- The power supply must take greater than or equal to 400  $\mu s$  to reach  $V_{CC}.$  Ramping to  $V_{CC}/V_{CCIO}$  earlier than 400  $\mu s$  can cause the device to behave improperly.

An internal diode is present in-between  $V_{CC}$  and  $V_{CCIO}$ , as shown in Figure 8.

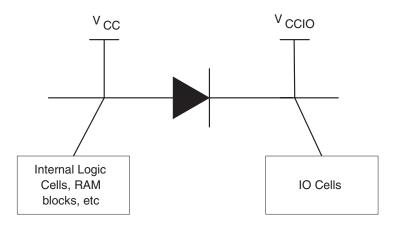


Figure 8: Internal Diode Between V<sub>CC</sub> and V<sub>CCIO</sub>

## **JTAG**

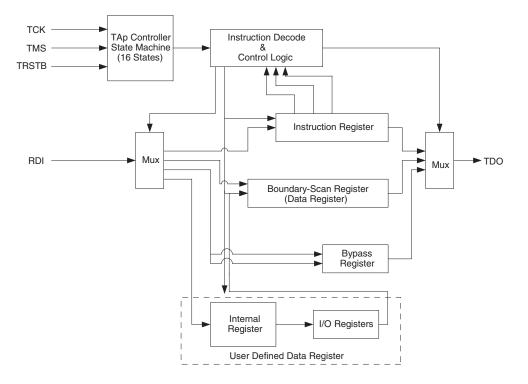


Figure 9: JTAG Block Diagram

Microprocessors and Application Specific Integrated Circuits (ASICs) pose many design challenges, not the least of which concerns the accessibility of test points. The Joint Test Access Group (JTAG) formed in response to this challenge, resulting in IEEE standard 1149.1, the Standard Test Access Port and Boundary Scan Architecture.

The JTAG boundary scan test methodology allows complete observation and control of the boundary pins of a JTAG-compatible device through JTAG software. A Test Access Port (TAP) controller works in concert with the Instruction Register (IR); these allow users to run three required tests, along with several user-defined tests.

JTAG tests allow users to reduce system debug time, reuse test platforms and tools, and reuse subsystem tests for fuller verification of higher level system elements.

The 1149.1 standard requires the following three tests:

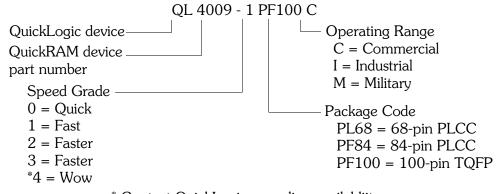
- **Extest Instruction.** The Extest instruction performs a PCB interconnect test. This test places a device into an external boundary test mode, selecting the boundary scan register to be connected between the TAP's Test Data In (TDI) and Test Data Out (TDO) pins. Boundary scan cells are preloaded with test patterns (via the Sample/Preload Instruction), and input boundary cells capture the input data for analysis.
- **Sample/Preload Instruction.** This instruction allows a device to remain in its functional mode, while selecting the boundary scan register to be connected between the TDI and TDO pins. For this test, the boundary scan register can be accessed via a data scan operation, allowing users to sample the functional data entering and leaving the device.
- **Bypass Instruction.** The Bypass instruction allows data to skip a device's boundary scan entirely, so the data passes through the bypass register. The Bypass instruction allows users to test a device without passing through other devices. The bypass register is connected between the TDI and TDO pins, allowing serial data to be transferred through a device without affecting the operation of the device.

## **Pin Descriptions**

| Pin               | Function   | Description   |
|-------------------|--|---|
| TDI/RSI           | Test Data In for JTAG /RAM init.<br>Serial Data In | Hold HIGH during normal operation. Connects to serial PROM data in for RAM initialization. Connect to $V_{\rm CC}$ if unused.   |
| TRSTB/RRO         | Active low Reset for JTAG /RAM init. reset out     | Hold LOW during normal operation. Connects to serial PROM reset for RAM initialization. Connect to GND if unused.               |
| TMS               | Test Mode Select for JTAG                          | Hold HIGH during normal operation. Connect to $V_{\text{CC}}$ if not used for JTAG.   |
| TCK               | Test Clock for JTAG                                | Hold HIGH or LOW during normal operation. Connect to $V_{CC}$ or ground if not used for JTAG.                                   |
| TDO/RCO           | Test data out for JTAG /RAM init.<br>clock out     | Connect to serial PROM clock for RAM initialization. Must<br>be left unconnected if not used for JTAG or RAM<br>initialization. |
| STM               | Special Test Mode                                  | Must be grounded during normal operation.   |
| I/ACLK            | High-drive input and/or array network driver       | Can be configured as either or both.  |
| I/GCLK            | High-drive input and/or global network driver      | Can be configured as either or both.  |
| Ι                 | High-drive input                                   | Use for input signals with high fanout.   |
| I/O               | Input/Output pin                                   | Can be configured as an input and/or output.  |
| V <sub>cc</sub>   | Power supply pin                                   | Connect to 3.3 V supply.  |
| V <sub>CCIO</sub> | Input voltage tolerance pin                        | Connect to $5.0$ V supply if 5 V input tolerance is required, otherwise connect to $3.3$ V supply.                              |
| GND               | Ground pin   | Connect to ground.  |
| GND/THERM         | Ground/Thermal pin                                 | Available on 456-PBGA only. Connect to ground plane on PCB if heat sinking desired. Otherwise may be left unconnected.          |

#### Table 12: Pin Descriptions

## **Ordering Information**



\* Contact QuickLogic regarding availabliity

### 68 PLCC Pinout Diagram

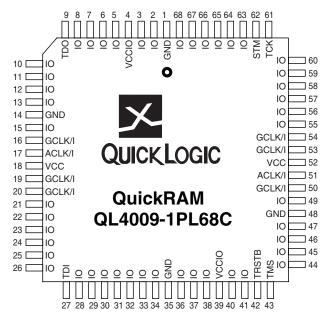


Figure 10: Top View of 68 Pin PLCC

Table 13: 68 PLCC Pinout Table

| 68 PLCC | Function |
|---------|----------|---------|----------|---------|----------|---------|----------|
| 1       | GND      | 18      | Vcc      | 35      | GND      | 52      | Vcc      |
| 2       | I/O      | 19      | GCLK/I   | 36      | I/O      | 53      | GCLK/I   |
| 3       | I/O      | 20      | GCLK/I   | 37      | I/O      | 54      | GCLK/I   |
| 4       | VCCIO    | 21      | I/O      | 38      | I/O      | 55      | I/O      |
| 5       | I/O      | 22      | I/O      | 39      | VCCIO    | 56      | I/O      |
| 6       | I/O      | 23      | I/O      | 40      | I/O      | 57      | I/O      |
| 7       | I/O      | 24      | I/O      | 41      | I/O      | 58      | I/O      |
| 8       | I/O      | 25      | I/O      | 42      | TRSTB    | 58      | I/O      |
| 9       | TDO      | 26      | I/O      | 43      | TMS      | 60      | I/O      |
| 10      | I/O      | 27      | TDI      | 44      | I/O      | 61      | TCK      |
| 11      | I/O      | 28      | I/O      | 45      | I/O      | 62      | STM      |
| 12      | I/O      | 29      | I/O      | 46      | I/O      | 63      | I/O      |
| 13      | I/O      | 30      | I/O      | 47      | I/O      | 64      | I/O      |
| 14      | GND      | 31      | I/O      | 48      | GND      | 65      | I/O      |
| 15      | I/O      | 32      | I/O      | 49      | I/O      | 66      | I/O      |
| 16      | GCLK/I   | 33      | I/O      | 50      | GCLK/I   | 67      | I/O      |
| 17      | ACLK/I   | 34      | I/O      | 51      | ACLK/I   | 68      | I/O      |

### **68 PLCC Pinout Table**

## 84 PLCC Pinout Diagram

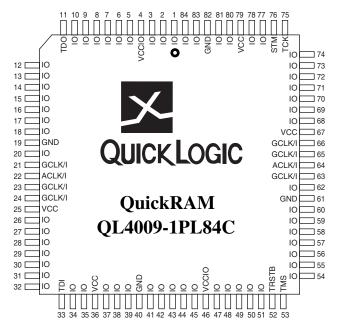


Figure 11: Top View of 84 Pin PLCC

## **84 PLCC Pinout Table**

| 84 PLCC | Function | 84 PLCC | Function        | 84 PLCC | Function | 84 PLCC | Function        |
|---------|----------|---------|-----------------|---------|----------|---------|-----------------|
| 1       | I/O      | 22      | ACLK/I          | 43      | I/O      | 64      | ACLK/I          |
| 2       | I/O      | 23      | GCLK/I          | 44      | I/O      | 65      | GCLK/I          |
| 3       | I/O      | 24      | GCLK/I          | 45      | I/O      | 66      | GCLK/I          |
| 4       | VCCIO    | 25      | VCC             | 46      | VCCIO    | 67      | V <sub>CC</sub> |
| 5       | I/O      | 26      | I/O             | 47      | I/O      | 68      | I/O             |
| 6       | I/O      | 27      | I/O             | 48      | I/O      | 69      | I/O             |
| 7       | I/O      | 28      | I/O             | 49      | I/O      | 70      | I/O             |
| 8       | I/O      | 29      | I/O             | 50      | I/O      | 71      | I/O             |
| 9       | I/O      | 30      | I/O             | 51      | I/O      | 72      | I/O             |
| 10      | I/O      | 31      | I/O             | 52      | TRSTB    | 73      | I/O             |
| 11      | TDO      | 32      | I/O             | 53      | TMS      | 74      | I/O             |
| 12      | I/O      | 33      | TDI             | 54      | I/O      | 75      | TCK             |
| 13      | I/O      | 34      | I/O             | 55      | I/O      | 76      | STM             |
| 14      | I/O      | 35      | I/O             | 56      | I/O      | 77      | I/O             |
| 15      | I/O      | 36      | V <sub>CC</sub> | 57      | I/O      | 78      | I/O             |
| 16      | I/O      | 37      | I/O             | 58      | I/O      | 79      | Vcc             |
| 17      | I/O      | 38      | I/O             | 59      | I/O      | 80      | I/O             |
| 18      | I/O      | 39      | I/O             | 60      | I/O      | 81      | I/O             |
| 19      | GND      | 40      | GND             | 61      | GND      | 82      | GND             |
| 20      | I/O      | 41      | I/O             | 62      | I/O      | 83      | I/O             |
| 21      | GCLK/I   | 42      | I/O             | 63      | GCLK/I   | 84      | I/O             |

#### Table 14: 84 PLCC Pinout Table

## **100 TQFP Pinout Diagram**

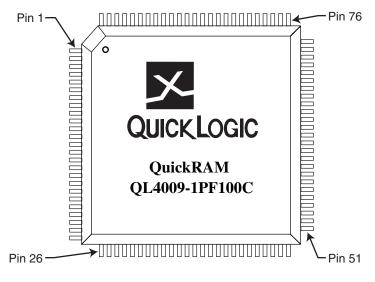


Figure 12: Top View of 100 Pin TQFP

## **100 TQFP Pinout Table**

| 100TQFP | Function | 100TQFP | Function | 100TQFP | Function | 100TQFP | Function |
|---------|----------|---------|----------|---------|----------|---------|----------|
| 1       | I/O      | 26      | TDI      | 51      | I/O      | 76      | тск      |
| 2       | I/O      | 27      | I/O      | 52      | I/O      | 77      | STM      |
| 3       | I/O      | 28      | I/O      | 53      | I/O      | 78      | I/O      |
| 4       | I/O      | 29      | I/O      | 54      | I/O      | 79      | I/O      |
| 5       | I/O      | 30      | I/O      | 55      | I/O      | 80      | I/O      |
| 6       | I/O      | 31      | I/O      | 56      | I/O      | 81      | I/O      |
| 7       | I/O      | 32      | I/O      | 57      | I/O      | 82      | I/O      |
| 8       | I/O      | 33      | I/O      | 58      | I/O      | 83      | I/O      |
| 9       | GND      | 34      | I/O      | 59      | GND      | 84      | I/O      |
| 10      | I/O      | 35      | GND      | 60      | I/O      | 85      | GND      |
| 11      | l        | 36      | I/O      | 61      | I        | 86      | I/O      |
| 12      | ACLK / I | 37      | I/O      | 62      | ACLK / I | 87      | I/O      |
| 13      | Vcc      | 38      | GND      | 63      | Vcc      | 88      | GND      |
| 14      | I        | 39      | I/O      | 64      | I        | 89      | I/O      |
| 15      | GCLK / I | 40      | I/O      | 65      | GCLK / I | 90      | I/O      |
| 16      | Vcc      | 41      | I/O      | 66      | Vcc      | 91      | I/O      |
| 17      | I/O      | 42      | VCCIO    | 67      | I/O      | 92      | VCCIO    |
| 18      | I/O      | 43      | I/O      | 68      | I/O      | 93      | I/O      |
| 19      | I/O      | 44      | I/O      | 69      | I/O      | 94      | I/O      |
| 20      | I/O      | 45      | I/O      | 70      | I/O      | 95      | I/O      |
| 21      | I/O      | 46      | I/O      | 71      | I/O      | 96      | I/O      |
| 22      | I/O      | 47      | I/O      | 72      | I/O      | 97      | I/O      |
| 23      | I/O      | 48      | I/O      | 73      | I/O      | 98      | I/O      |
| 24      | I/O      | 49      | TRSTB    | 74      | I/O      | 99      | I/O      |
| 25      | I/O      | 50      | TMS      | 75      | I/O      | 100     | TDO      |

Table 15: 100 TQFP Pinout Table

### **Contact Information**

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|------------|----------------------------|
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|            | 44 1932 57 9011 (Europe)   |
|            | 49 89 930 86 170 (Germany) |
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|            | 81 45 470 5525 (Japan)     |
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| Support:   | support@quicklogic.com     |
| Web site:  | http://www.quicklogic.com/ |

### **Revision History**

Table 16: Revision History

| Revision | Date   | Comments   |
|----------|--------|--|
| А        | 5/2000 | First release.   |
| В        | 5/2002 | Added Kfactor, Power-up, JTAG and mechanical drawing information. Reformatted. |

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